

PBHV9560Z

600 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor
12 August 2014 **Product data sheet**

1. **General description**

PNP high-voltage low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBHV8560Z

2. **Features and benefits**

- High voltage
- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C
- High collector current gain hFE at high IC
- AEC-Q101 qualified

Applications

- Electronic ballast for fluorescent lighting
- LED driver for LED chain module
- LCD backlighting
- HID front lighting
- Automotive motor management
- Hook switch for wired telecom
- Switch Mode Power Supply (SMPS)

Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-600	V
I _C	collector current		_	-	-0.5	Α
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -50 mA; T_{amb} = 25 °C	70	130	-	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	2, 4
2	С	collector		1—
3	Е	emitter		
4	С	collector	⊟1 ⊟2 ⊟3 SC-73 (SOT223)	3 sym028

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PBHV9560Z	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

7. Marking

Table 4. Marking codes

Type number	Marking code
PBHV9560Z	HV956Z

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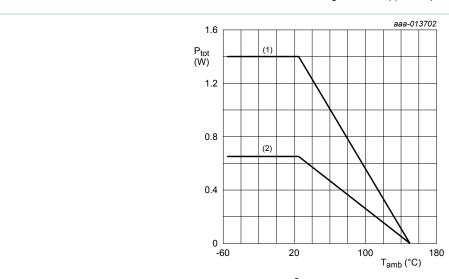
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-600	V
V_{CEO}	collector-emitter voltage	open base		-	-600	V
V _{CESM}	collector-emitter peak voltage	V _{BE} = 0 V		-	-600	V
V_{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-0.5	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.65	W
			<u>[2]</u>	-	1.4	W
T_{j}	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, standard footprint

Fig. 1. Power derating curves

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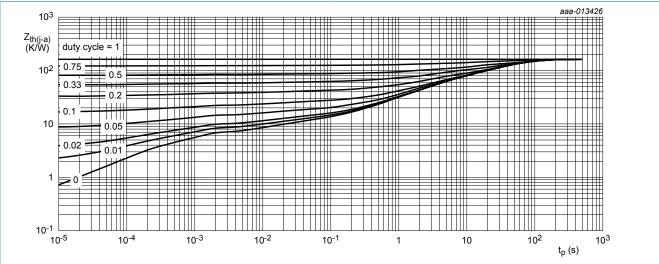
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Thermal characteristics

Table 6. **Thermal characteristics**

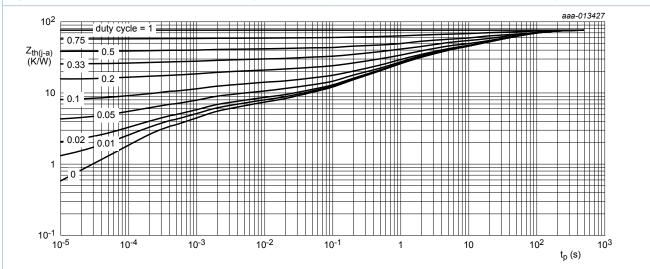
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	190	K/W
			<u>[2]</u>	-	-	89	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	20	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².



FR4 PCB, single-sided copper, tin-plated and standard footprint.

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 2.



FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

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Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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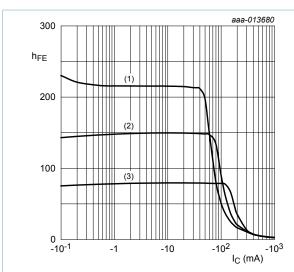
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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V_{CB} = -400 V; I_E = 0 A; T_{amb} = 25 °C	-	-	-100	nA
	current	V_{CB} = -400 V; I_{E} = 0 A; T_{j} = 150 °C	-	-	-10	μA
I _{CES}	collector-emitter cut-off current	$V_{CE} = -400 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h _{FE} D	DC current gain	V_{CE} = -10 V; I_{C} = -50 mA; T_{amb} = 25 °C	70	130	-	
		V_{CE} = -10 V; I_{C} = -100 mA; pulsed; $t_{p} \le 300 \ \mu s$; $\delta \le 0.02$; T_{amb} = 25 °C	50	90	-	
V _{CEsat}	collector-emitter	I_C = -50 mA; I_B = -5 mA; T_{amb} = 25 °C	-	-150	-250	mV
satu	saturation voltage	I_{C} = -100 mA; I_{B} = -20 mA; pulsed; t_{p} ≤ 300 µs; δ ≤ 0.02; T_{amb} = 25 °C	-	-140	-250	mV
V _{BEsat}	base-emitter saturation voltage	I_{C} = -50 mA; I_{B} = -5 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	-	-	-900	mV
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -30 mA; f = 100 MHz	-	38	-	MHz
C _c	collector capacitance	V_{CB} = -20 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	12	-	pF
C _e	emitter capacitance	V_{EB} = -0.5 V; I_{C} = 0 A; i_{c} = 0 A; f = 1 MHz; T_{amb} = 25 °C	-	390	-	pF

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$$V_{CE} = -10 \text{ V}$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values

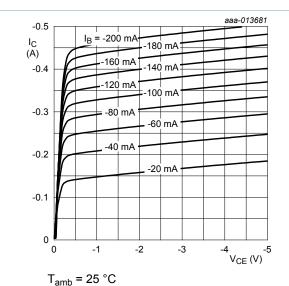
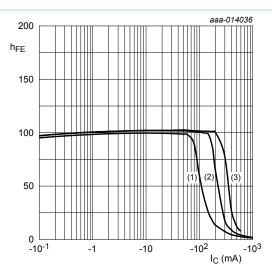


Fig. 6. Collector current as a function of collectoremitter voltage; typical values



$$h_{FE} = f_{(IC)}$$

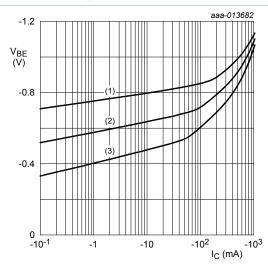
$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$V_{CE} = -10 \text{ V}$$

(2)
$$V_{CE} = -25 \text{ V}$$

(3)
$$V_{CE} = -50 \text{ V}$$

Fig. 5. DC current gain as a function of collector current; typical values



$$V_{CE} = -5 V$$

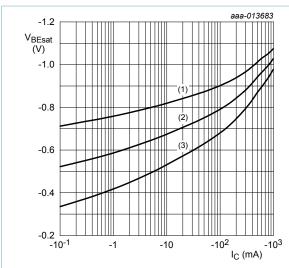
(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C

Fig. 7. Base-emitter voltage as a function of collector current; typical values

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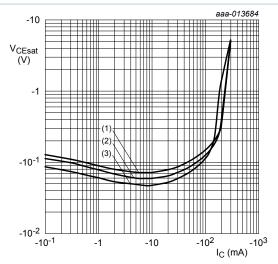


$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C



$$I_C/I_B = 5$$

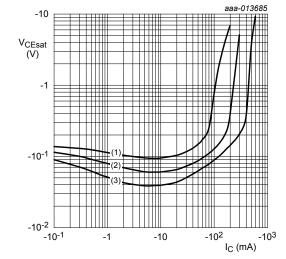
(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values





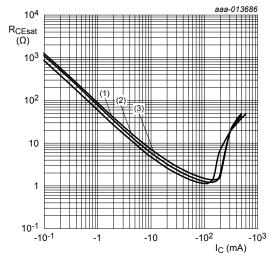
$$T_{amb} = 25 \, ^{\circ}C$$

(1)
$$I_C/I_B = 10.0$$

(2)
$$I_C/I_B = 5.0$$

(3)
$$I_C/I_B = 2.5$$

Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 5$$

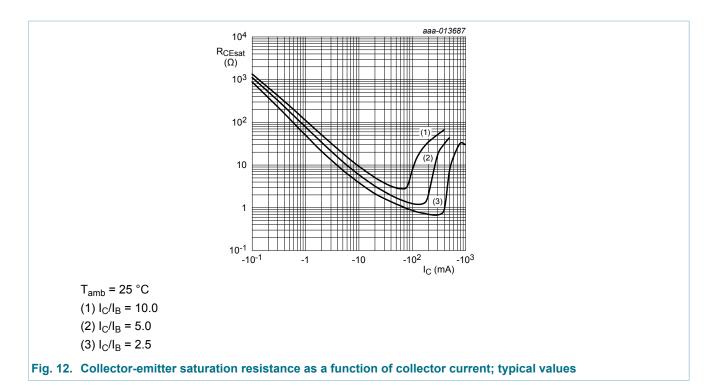
(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values

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11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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12. Package outline

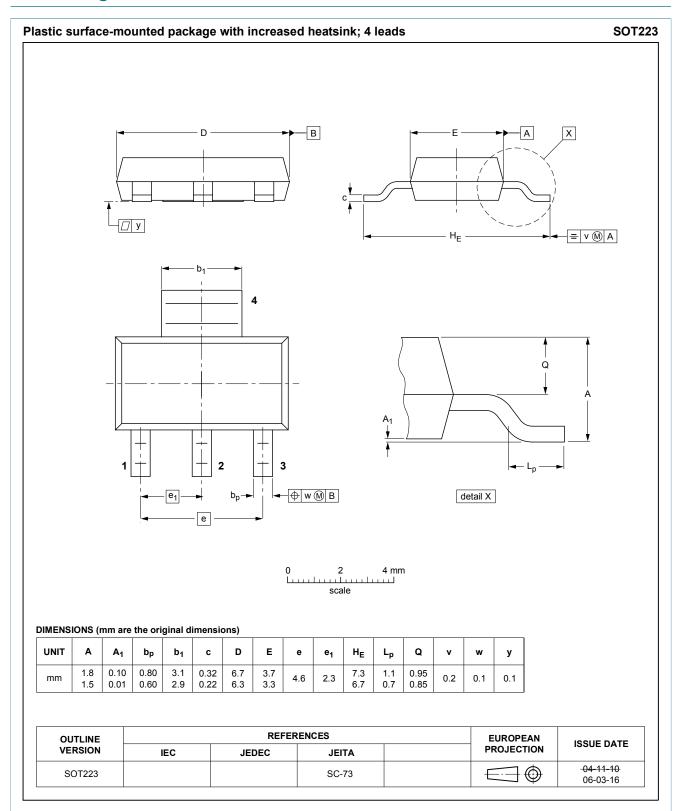


Fig. 13. Package outline SC-73 (SOT223)

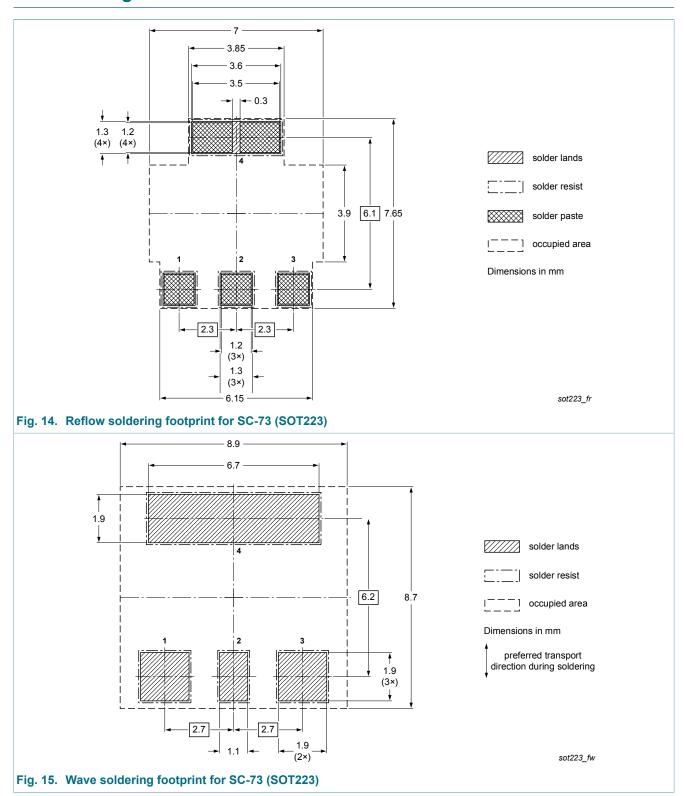
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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBHV9560Z v.1	20140812	Product data sheet	-	-

600 V, 0.5 A PNP high-voltage low VCEsat (BISS) transistor

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